

N-Channel 60 V (D-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	$R_{DS(on)}(\Omega)$	$I_D(A)^{a, e} Q_g(Ty)$				
60	0.0025 at V _{GS} = 10 V	150	82 nC			
00	0.0032 at $V_{GS} = 4.5 \text{ V}$	130	02 110			

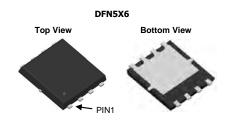
FEATURES

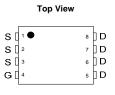
- **DT-Trench Power MOSFET**
- 100 % R_g and UIS Tested

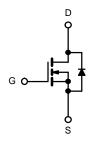


APPLICATIONS

- · Notebook PC Core
- VRM/POL







N-Channel MOSFET

Parameter	Symbol	Limit	Unit		
Drain-Source Voltage		V _{DS}	60	V	
Gate-Source Voltage		V_{GS}	± 20		
	T _C = 25 °C		150 ^{a, e}		
Continuous Drain Current (T. – 175 °C)	T _C = 70 °C	_	130 ^e		
Continuous Drain Current (T _J = 175 °C)	T _A = 25 °C	I _D	25 ^{b, c}	A	
	T _A = 70 °C		22.8 ^{b, c}	_ ^	
Pulsed Drain Current		I _{DM}	280		
Avalanche Current Pulse	L = 0.1 mH	I _{AS}	35		
Single Pulse Avalanche Energy	L = 0.1 IIII1	E _{AS}	250	mJ	
Continuous Source-Drain Diode Current	T _C = 25 °C	I _S	150 ^{a, e}	А	
Continuous Source-Drain Diode Current	T _A = 25 °C	'S	4.68 ^{b, c}		
	T _C = 25 °C		210 ^a		
Maximum Power Dissipation	T _C = 70 °C	P _D	147	w	
	T _A = 25 °C	טי	5.05 ^{b, c}	vv	
	T _A = 70 °C		3.56 ^{b, c}		
Operating Junction and Storage Temperature R	T _J , T _{stg}	- 55 to 175	°C		

THERMAL RESISTANCE RATINGS							
Parameter		Symbol	Typical	Maximum	Unit		
Maximum Junction-to-Ambient ^{b, d}	t ≤ 10 s	R_{thJA}	16	21	°C/W		
Maximum Junction-to-Case	Steady State	R _{thJC}	0.6	1.0	C/VV		

Notes:

- a. Based on T_C = 25 °C. b. Surface mounted on 1" x 1" FR4 board.
- d. Maximum under steady state conditions is 90 °C/W.
- e. Calculated based on maximum junction temperature. Package limitation current is 80 A.



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Parameter	Symbol	Test Conditions	Min .	Тур.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	60			V
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	I _D = 250 μA		35		mV/°C
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_{J}$	ι _D = 230 μΑ		- 5.5		
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1.0		2.5	V
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA
Zara Cata Valtaga Drain Current	I _{DSS}	V _{DS} = 48 V, V _{GS} = 0 V			1	μΑ
Zero Gate Voltage Drain Current		V _{DS} = 48 V, V _{GS} = 0 V, T _J = 55 °C			10	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	150			Α
	D	$V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}$		0.0025	0.0030	Ω
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 20 \text{ A}$		0.0032	0.0035	
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 15 \text{ V}, I_D = 15 \text{ A}$		50		S
Dynamic ^b			•			
Input Capacitance	C _{iss}			3895		pF
Output Capacitance	C _{oss}	V_{DS} = 12.5 V, V_{GS} = 0 V, f = 1 MHz		875		
Reverse Transfer Capacitance	C _{rss}			22		
Total Cata Charge	Qg	$V_{DS} = 15 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}$		82		nC
Total Gate Charge				67.5		
Gate-Source Charge	Q_{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 20 \text{ A}$		12		
Gate-Drain Charge	Q_{gd}			14		
Gate Resistance	R_g	f = 1 MHz	MHz		2.1	Ω
Turn-On Delay Time	t _{d(on)}			17	22	
Rise Time	t _r	V_{DD} = 15 V, R_L = 0.555 Ω		11	15	ns
Turn-Off Delay Time	t _{d(off)}	$I_D\cong 27$ A, $V_{GEN}=10$ V, $R_g=1$ Ω		25	45	
Fall Time	t _f			4	8	
Turn-On Delay Time	t _{d(on)}			8	13	
Rise Time	t _r	V_{DD} = 15 V, R_L = 0.625 Ω		82	125	
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ 24 A, V_{GEN} = 4.5 V, R_g = 1 Ω		22	43	
Fall Time	t _f			10	15	
Drain-Source Body Diode Characteristics	3					
Continuous Source-Drain Diode Current	I _S	T _C = 25 °C			150	Δ
Pulse Diode Forward Current ^a	I _{SM}				280	A
Body Diode Voltage	V_{SD}	I _S = 22 A		0.8	1.2	V
Body Diode Reverse Recovery Time	t _{rr}			55	78	ns
Body Diode Reverse Recovery Charge	Q _{rr}	$I_F = 20 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}, T_J = 25 \text{ °C}$		80.2	112	nC
Reverse Recovery Fall Time	t _a	$_{1F} = 20 \text{ A}$, $_{UV}UI = 100 \text{ AV}\mu \text{S}$, $_{IJ} = 25 \text{ C}$		27		ns
Reverse Recovery Rise Time	t _b			25		

Notes:

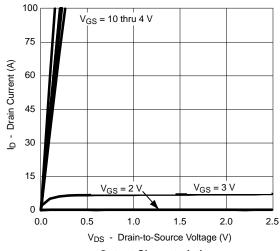
- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

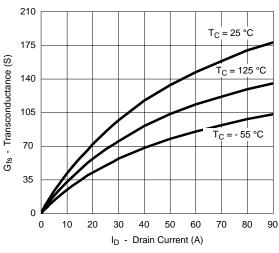


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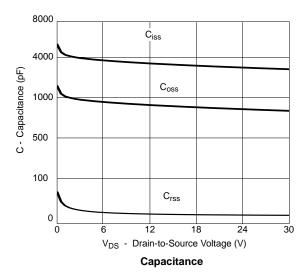
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

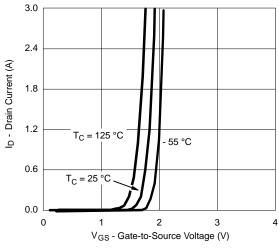


Output Characteristics

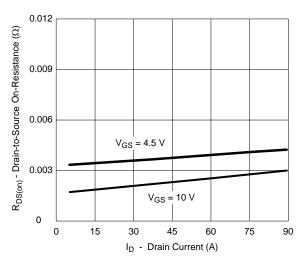


Transconductance

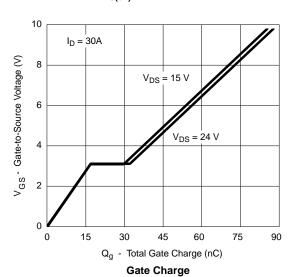




Transfer Characteristics

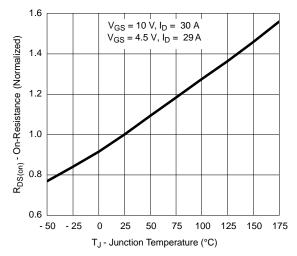


R_{DS(on)} vs. Drain Current

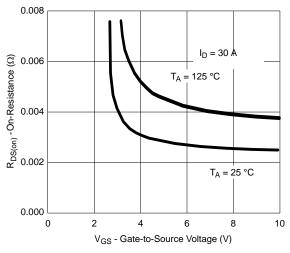




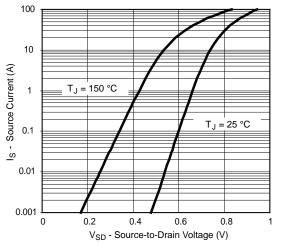
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



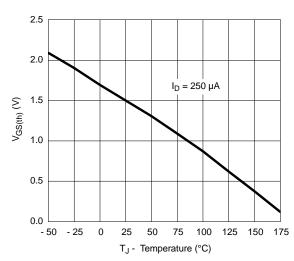
On-Resistance vs. Junction Temperature



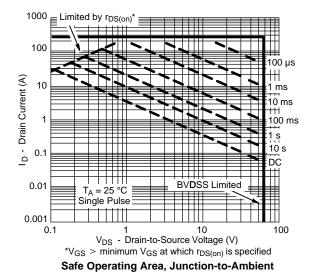
 $\rm R_{\rm DS(on)}$ vs. $\rm V_{\rm GS}$ vs. Temperature

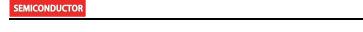


Forward Diode Voltage vs. Temperature



Threshold Voltage

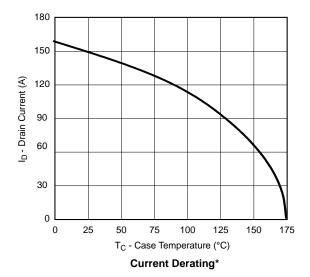


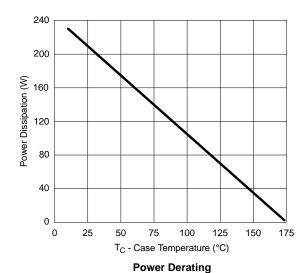


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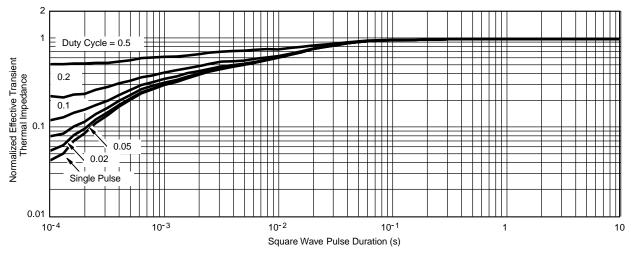
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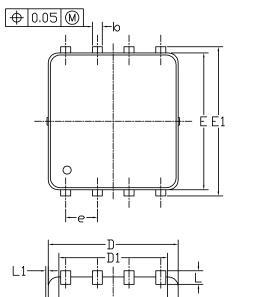
* The power dissipation P_D is based on $T_{J(max)} = 175$ °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

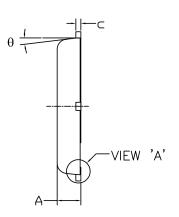


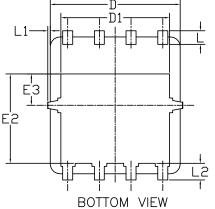
Normalized Thermal Transient Impedance, Junction-to-Case

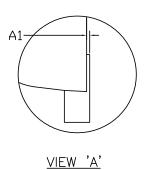


DFN5x6_8L_EP1_P PACKAGE OUTLIN



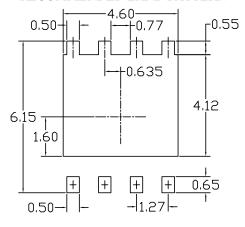






(SCALE 5:1)

RECOMMENDED LAND PATTERN



SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES			
3 I MBOLS	MIN	NOM	MAX	MIN	NOM	MAX	
A	0.85	0. 95	1.00	0.033	0.037	0.039	
Al	0.00		0.05	0.000		0.002	
b	0.30	0.40	0.50	0.012	0.016	0.020	
c	0. 15	0. 20	0. 25	0.006	0.008	0.010	
D	4. 80	5. 20	5. 30	0. 201	0. 205	0. 209	
D1	4. 25	4. 35	4. 45	0. 167	0.171	0. 175	
Е	5. 45	5. 55	5. 65	0. 215	0. 219	0. 222	
E1	5. 95	6.05	6. 15	0. 234	0. 238	0. 242	
E2	3. 525	3.625	3. 725	0. 139	0. 143	0. 147	
E3	1. 175	1. 275	1. 375	0.046	0.050	0.054	
e	1. 27 BSC			0.050 BSC			
L	0.45	0. 55	0.65	0.018	0.022	0.026	
L1	0		0. 15	0		0.006	
L2	0.68 REF			0.027 REF			
θ	0°		10°	0°		10°	

NOTE

- 1. PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS.
 MOLD FLASH AT THE NON-LEAD SIDES SHOULD BE LESS THAN 6 MILS EACH.
- 2. CONTROLLING DIMENSION IS MILLIMETER. CONVERTED INCH DIMENSIONS ARE NOT NECESSARILY EXACT.

UNIT: mm

1





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